

## SAMYANG ELECTRONICS MBR1620CT --- MBR16200CT

## SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 200 V CURRENT:16.0A

### **FEATURES**

- Metal-semiconductor junction with guard ring

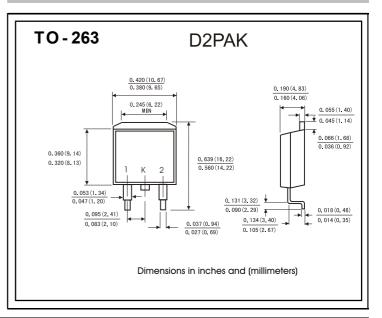
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications

#### **MECHANICAL DATA**

- $\bigcirc$  Terminals: Axial lead ,solderable per

MIL-STD-202, Method 208

- ◇Polarity: As marked
- ♦ Weight: 0.08ounces,2.24 grams



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

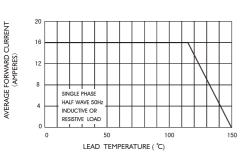
|  |                        | Symbols         | MBR<br>1620CT | MBR<br>1630CT         | MBR<br>1640CT | MBR<br>1650CT | MBR<br>1660CT | MBR<br>1680CT | MBR<br>16100CT | MBR<br>16150CT | MBR<br>16200CT | Units |
|--|------------------------|-----------------|---------------|-----------------------|---------------|---------------|---------------|---------------|----------------|----------------|----------------|-------|
| Maximum repetitive peak reverse voltage  |                        | Vrrm            | 20            | 30                    | 40            | 50            | 60            | 80            | 100            | 150            | 200            | Volts |
| Maximum RMS voltage  |                        | VRMS            | 14            | 21                    | 28            | 35            | 42            | 56            | 70             | 105            | 140            | Volts |
| Maximum DC blocking voltage  |                        | VDC             | 20            | 30                    | 40            | 50            | 60            | 80            | 100            | 150            | 200            | Volts |
| Maximum average forward rectified current(see Fig.1)   | Per leg<br>otal device | I(AV)           | 8.0<br>16.0   |                       |               |               |               |               |                |                | Amps           |       |
| Peak forward surge current 8.3ms single half<br>sine-wave superimposed on rated load<br>(JEDEC method) |                        | <b>I</b> FSM    | 200.0         |                       |               |               |               |               |                |                | Amps           |       |
| Maximum instantaneous forward voltage at 16.0 A  |                        | VF              |               | 0.60 0.75 0.85 0.90 0 |               |               |               | 0. 95         | Volts          |                |                |       |
| Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)                             | T <sub>c</sub> =25°C   | 1-              | 0.2           |                       |               |               |               |               |                |                |                |       |
|  | T <sub>c</sub> = 125°C | <b>I</b> R      |               | 30                    |               |               |               | 50            |                |                |                | mA    |
| Typical thermal resistance (Note 2)  |                        | $R_{\theta}$ JC | 3. 0          |                       |               |               |               |               |                |                |                | °C/W  |
| Operating junction temperature range   |                        | TJ              | -65 to+150    |                       |               |               |               |               |                |                |                | °C    |
| Storage temperature range  |                        | TstG            | -65 to+150    |                       |               |               |               |               |                |                |                | °C    |

NOTE: 1. Pulse test:300us pulse width,1% duty cycle.

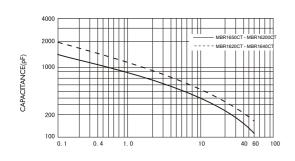
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance junction to ambient

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## FIG.1-FORWARD CURRENT DERATING CURVE

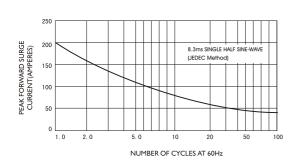


## FIG.4-TYPICAL JUNCTION CAPACITANCE

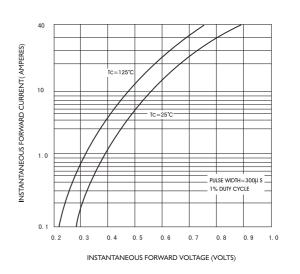


REVERSE VOLTAGE (VOLTS)

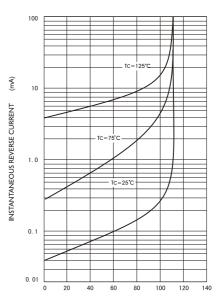
# FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



# FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



### FIG.3-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

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